

Remarks on the nature of Urbach absorption tail in glassy semiconductors

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Abstract

Exponential absorption edge of chalcogenide glassy alloys with sulfur content in the region of the topological transition is studied. It is shown that the slope of the tail ($1/\Delta$) depends on the mean coordination number ($r\sim$), the mean volume occupied by an atom (V) and the stoichiometry (Ω) of the materials, i. s. $\Delta = f(r\sim, V, \Omega)$. Analysis of the experimental results for alloys As-S-Ge as well as for other amorphous materials, including the elemental ones indicates that the topological disorder controlled by $r\sim$, Ω and V is the main reason in formation of the exponential absorption tail.

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